

# BTA312 series CT and ET

12 A Three-quadrant triacs high commutation high temperature

Rev. 01 — 6 April 2007

Product data sheet

## 1. Product profile

### 1.1 General description

Passivated, new generation, high commutation, high temperature triacs in a SOT78 plastic package

### 1.2 Features

- High operating junction temperature
- Very high commutation performance maximized at each gate sensitivity
- High immunity to dV/dt

### 1.3 Applications

- High temperature, high power motor control - e.g. vacuum cleaners
- Refrigeration and air conditioning compressors
- Heating and cooking appliances
- Non-linear rectifier-fed motor loads
- Electronic thermostats for heating and cooling loads
- Solid state relays

### 1.4 Quick reference data

- $V_{\text{DRM}} \leq 600 \text{ V}$  (BTA312-600CT)
- $V_{\text{DRM}} \leq 800 \text{ V}$  (BTA312-800ET)
- $I_{\text{TSM}} \leq 95 \text{ A}$  ( $t = 20 \text{ ms}$ )
- $I_{\text{GT}} \leq 35 \text{ mA}$  (BTA312-600CT)
- $I_{\text{GT}} \leq 10 \text{ mA}$  (BTA312-800ET)
- $I_{\text{T(RMS)}} \leq 12 \text{ A}$

## 2. Pinning information

Table 1. Pinning

Pin	Description	Simplified outline	Symbol
1	main terminal 1 (T1)	<p>SOT78 (TO-220AB)</p>	<p>sym051</p>
2	main terminal 2 (T2)		
3	gate (G)		
mb	mounting base; main terminal 2 (T2)		

### 3. Ordering information

**Table 2.** Ordering information

Type number	Package		Version
	Name	Description	
BTA312-600CT	SC-46	plastic single-ended package; heatsink mounted; 1 mounting hole;	SOT78
BTA312-800ET		3-lead TO-220AB	

### 4. Limiting values

**Table 3.** Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>DRM</sub>	repetitive peak off-state voltage	BTA312-600CT	[1] -	600	V
		BTA312-800ET	-	800	V
I <sub>T(RMS)</sub>	RMS on-state current	full sine wave; T <sub>mb</sub> ≤ 126 °C; see Figure 4 and 5	-	12	A
I <sub>TSM</sub>	non-repetitive peak on-state current	full sine wave; T <sub>j</sub> = 25 °C prior to surge; see Figure 2 and 3			
		t = 20 ms	-	95	A
		t = 16.7 ms	-	105	A
I <sup>2</sup> t	I <sup>2</sup> t for fusing	t = 10 ms	-	45	A <sup>2</sup> s
di <sub>T</sub> /dt	rate of rise of on-state current	I <sub>TM</sub> = 20 A; I <sub>G</sub> = 0.2 A; di <sub>G</sub> /dt = 0.2 A/μs	-	100	A/μs
I <sub>GM</sub>	peak gate current		-	2	A
P <sub>GM</sub>	peak gate power		-	5	W
P <sub>G(AV)</sub>	average gate power	over any 20 ms period	-	0.5	W
T <sub>stg</sub>	storage temperature		-40	+150	°C
T <sub>j</sub>	junction temperature		-	150	°C

- [1] Although not recommended, off-state voltages up to 800 V may be applied without damage, but the triac may switch to the on-state. The rate of rise of current should not exceed 15 A/μs.

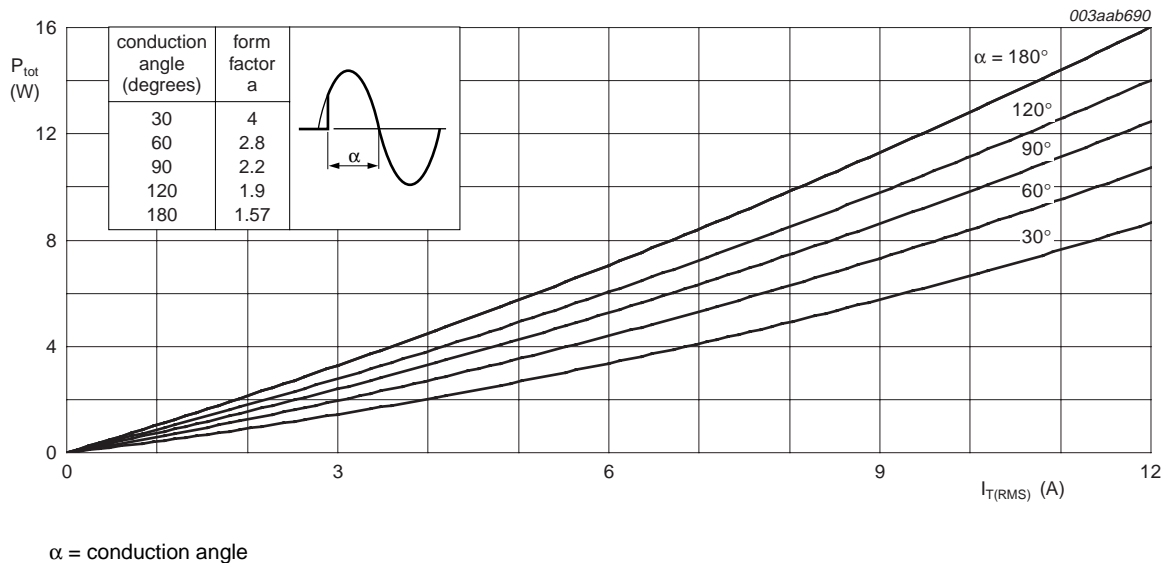


Fig 1. Total power dissipation as a function of RMS on-state current; maximum values

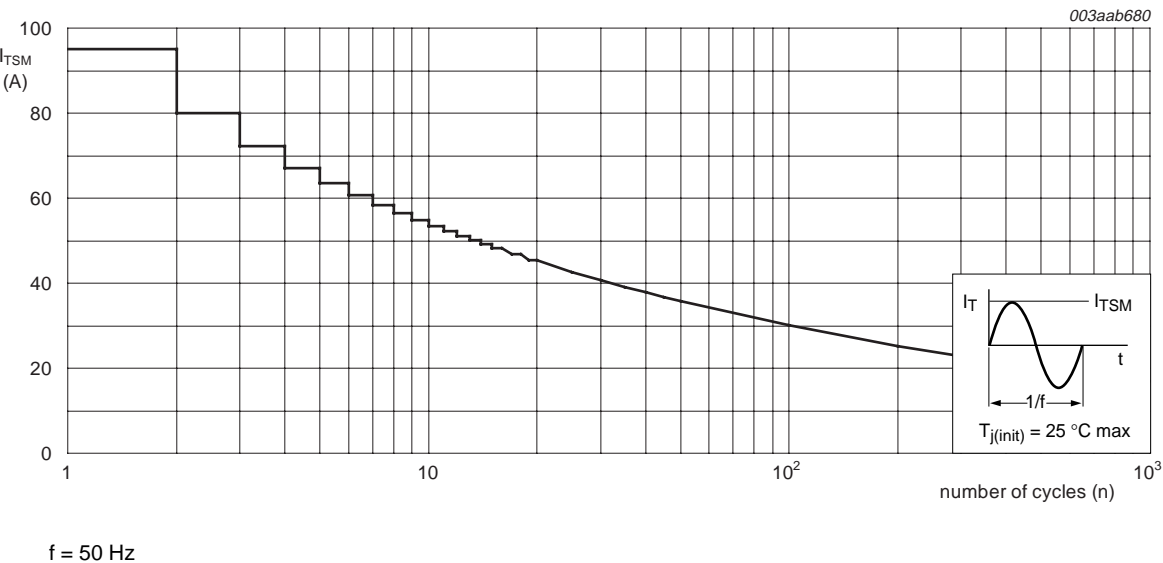
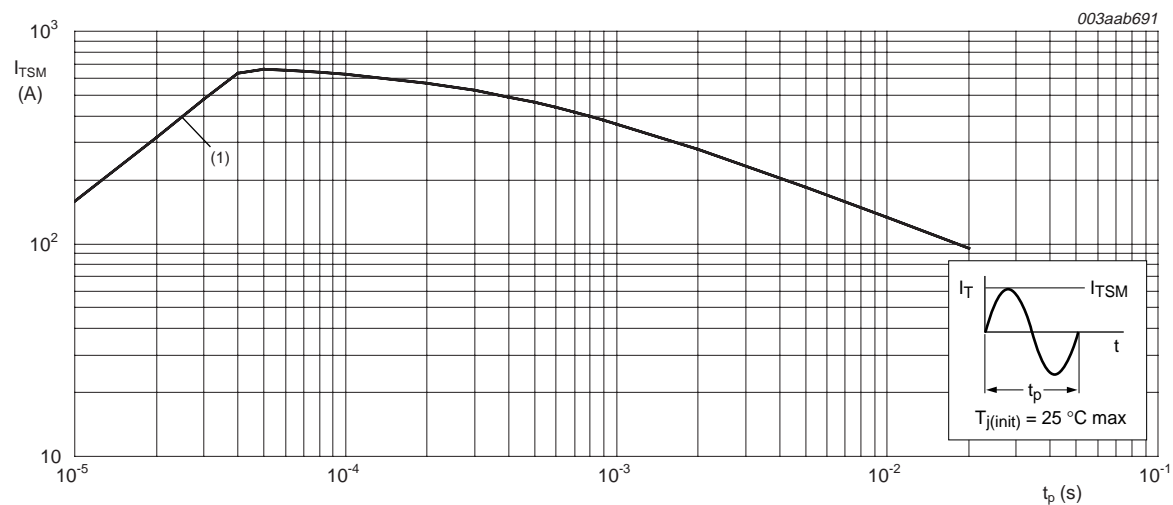
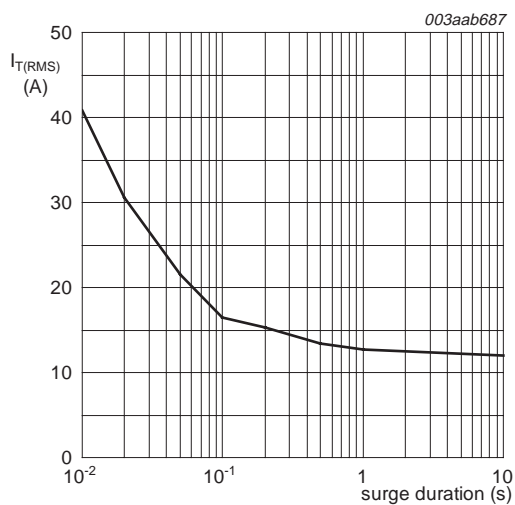


Fig 2. Non-repetitive peak on-state current as a function of the number of sinusoidal current cycles; maximum values



$t_p \leq 20$  ms  
(1)  $dI_T/dt$  limit

Fig 3. Non-repetitive peak on-state current as a function of pulse duration; maximum values



$f = 50$  Hz  
 $T_{mb} = 126^\circ\text{C}$

Fig 4. RMS on-state current as a function of surge duration; maximum values

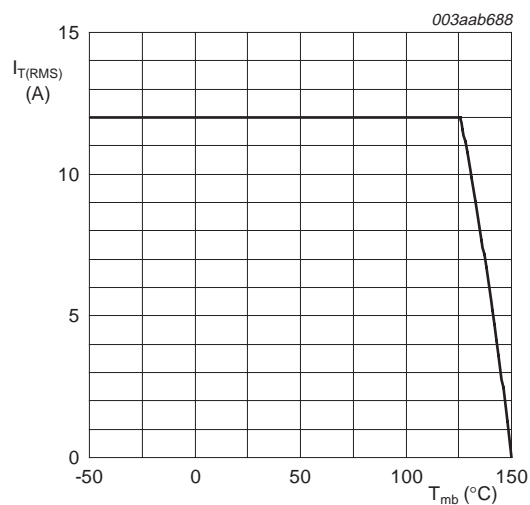
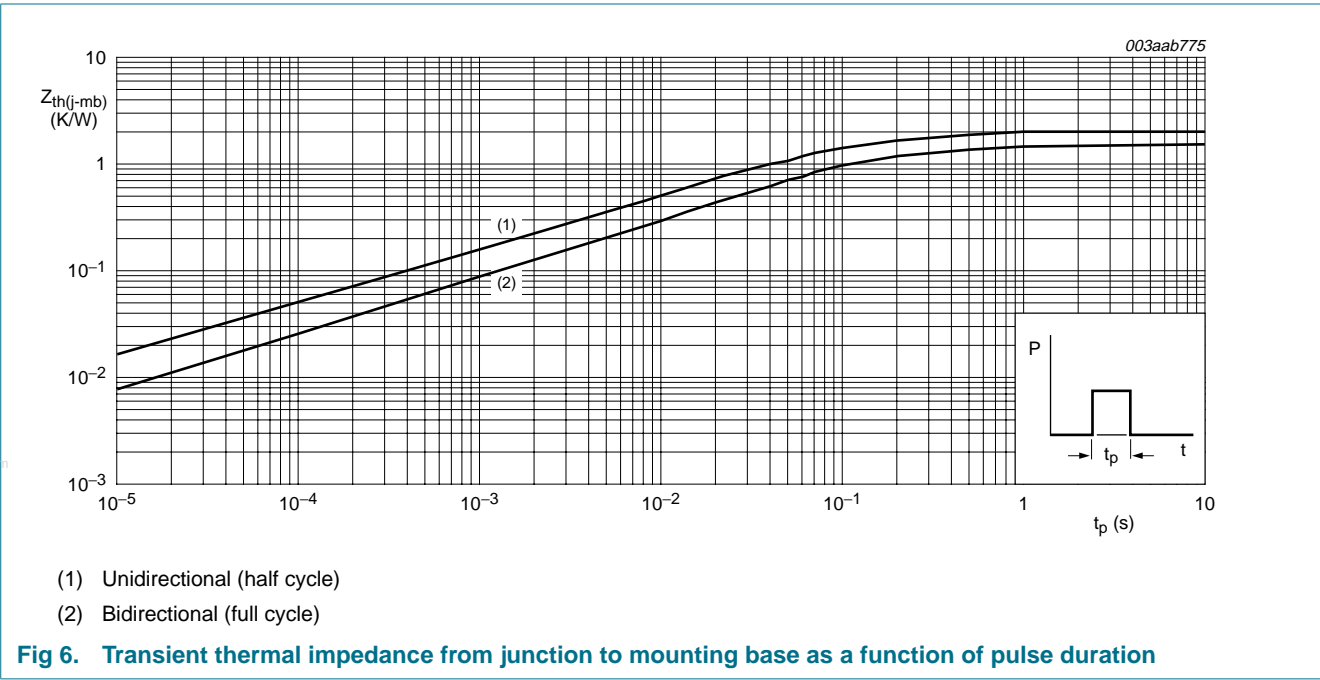


Fig 5. RMS on-state current as a function of mounting base temperature; maximum values

5. Thermal characteristics

Table 4. Thermal characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	half cycle; see <a href="#">Figure 6</a>	-	-	2.0	K/W
		full cycle; see <a href="#">Figure 6</a>	-	-	1.5	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	-	60	-	K/W



## 6. Static characteristics

**Table 5. Static characteristics**

$T_j = 25\text{ °C}$  unless otherwise specified.

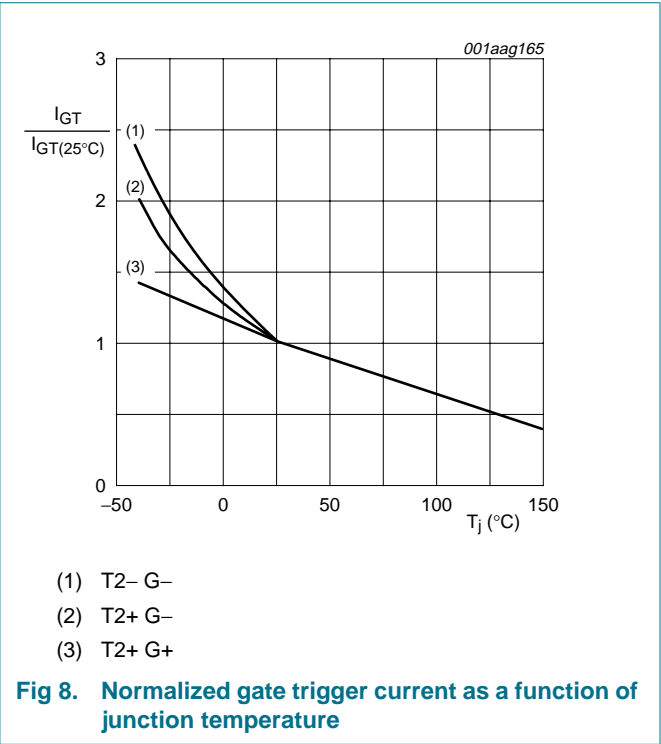
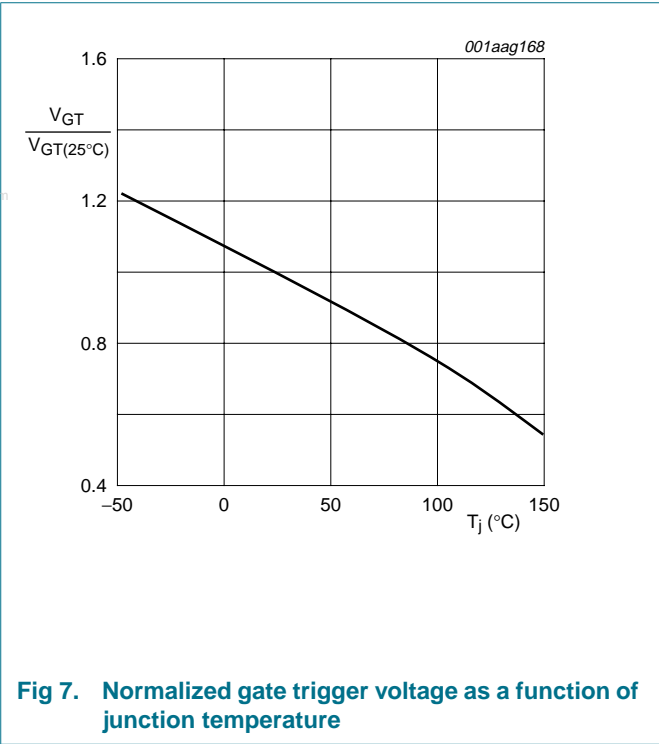
Symbol	Parameter	Conditions	BTA312-600CT			BTA312-800ET			Unit
			Min	Typ	Max	Min	Typ	Max	
$I_{GT}$	gate trigger current	$V_D = 12\text{ V}$ ; $I_T = 0.1\text{ A}$ ; see <a href="#">Figure 8</a>							
		T2+ G+	2	-	35	-	-	10	mA
		T2+ G-	2	-	35	-	-	10	mA
		T2- G-	2	-	35	-	-	10	mA
$I_L$	latching current	$V_D = 12\text{ V}$ ; $I_{GT} = 0.1\text{ A}$ ; see <a href="#">Figure 10</a>							
		T2+ G+	-	-	50	-	-	25	mA
		T2+ G-	-	-	60	-	-	30	mA
		T2- G-	-	-	50	-	-	25	mA
$I_H$	holding current	$V_D = 12\text{ V}$ ; $I_{GT} = 0.1\text{ A}$ ; see <a href="#">Figure 11</a>	-	-	35	-	-	15	mA
$V_T$	on-state voltage	$I_T = 15\text{ A}$ ; see <a href="#">Figure 9</a>	-	1.3	1.6	-	1.3	1.6	V
$V_{GT}$	gate trigger voltage	$V_D = 12\text{ V}$ ; $I_T = 0.1\text{ A}$ ; see <a href="#">Figure 7</a>	-	0.8	1.5	-	0.7	1.5	V
		$V_D = 400\text{ V}$ ; $I_T = 0.1\text{ A}$ ; $T_j = 150\text{ °C}$	0.25	-	-	0.25	-	-	V
$I_D$	off-state current	$V_D = V_{DRM(max)}$ ; $T_j = 150\text{ °C}$	-	0.4	2	-	0.4	2	mA

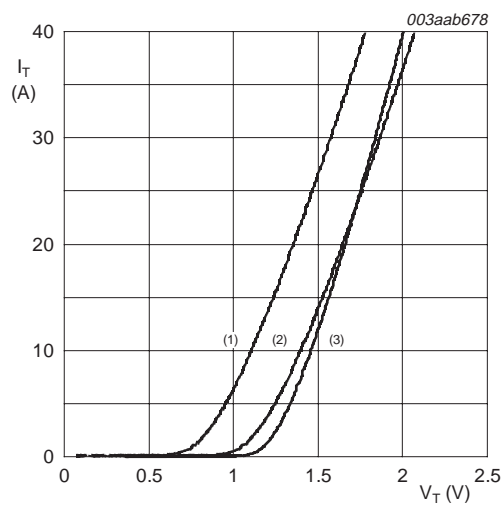
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7. Dynamic characteristics

Table 6. Dynamic characteristics

Symbol	Parameter	Conditions	BTA312-600CT			BTA312-800ET			Unit
			Min	Typ	Max	Min	Typ	Max	
$dV_D/dt$	rate of rise of off-state voltage	$V_{DM} = 0.67 \times V_{DRM(max)}$ ; $T_j = 150\text{ }^{\circ}\text{C}$ ; exponential waveform; gate open circuit	300	-	-	30	-	-	V/ $\mu\text{s}$
$di_{com}/dt$	rate of change of commutating current	$V_{DM} = 400\text{ V}$ ; $T_j = 150\text{ }^{\circ}\text{C}$ ; $I_{T(RMS)} = 12\text{ A}$ ; without snubber; gate open circuit	8	-	-	2	-	-	A/ms
		$V_{DM} = 400\text{ V}$ ; $T_j = 150\text{ }^{\circ}\text{C}$ ; $I_{T(RMS)} = 12\text{ A}$ ; $dV/dt = 10\text{ V}/\mu\text{s}$ ; gate open circuit	13	-	-	3.5	-	-	A/ms
		$V_{DM} = 400\text{ V}$ ; $T_j = 150\text{ }^{\circ}\text{C}$ ; $I_{T(RMS)} = 12\text{ A}$ ; $dV/dt = 1\text{ V}/\mu\text{s}$ ; gate open circuit	20	-	-	5	-	-	A/ms
$t_{gt}$	gate-controlled turn-on time	$I_{TM} = 20\text{ A}$ ; $V_D = V_{DRM(max)}$ ; $I_G = 0.1\text{ A}$ ; $di_G/dt = 5\text{ A}/\mu\text{s}$	-	2	-	-	2	-	$\mu\text{s}$





$V_O = 1.127 \text{ V}$

$R_S = 0.027 \text{ } \Omega$

- (1)  $T_j = 150 \text{ } ^\circ\text{C}$ ; typical values
- (2)  $T_j = 150 \text{ } ^\circ\text{C}$ ; maximum values
- (3)  $T_j = 25 \text{ } ^\circ\text{C}$ ; maximum values

Fig 9. On-state current as a function of on-state voltage

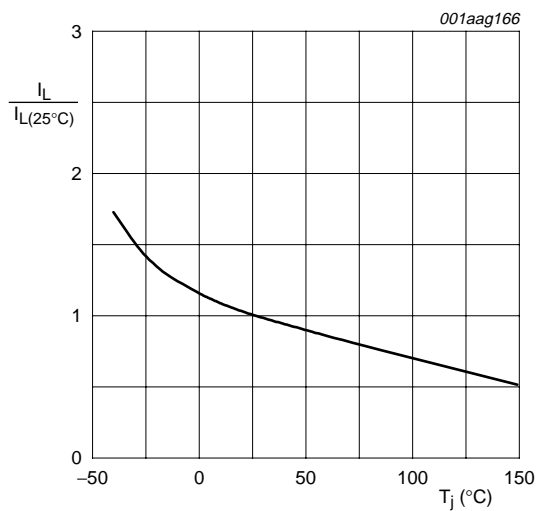


Fig 10. Normalized latching current as a function of junction temperature

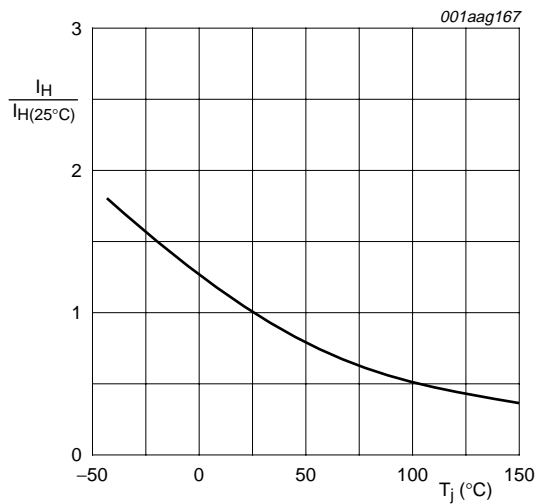


Fig 11. Normalized holding current as a function of junction temperature

8. Package outline

Plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB

SOT78

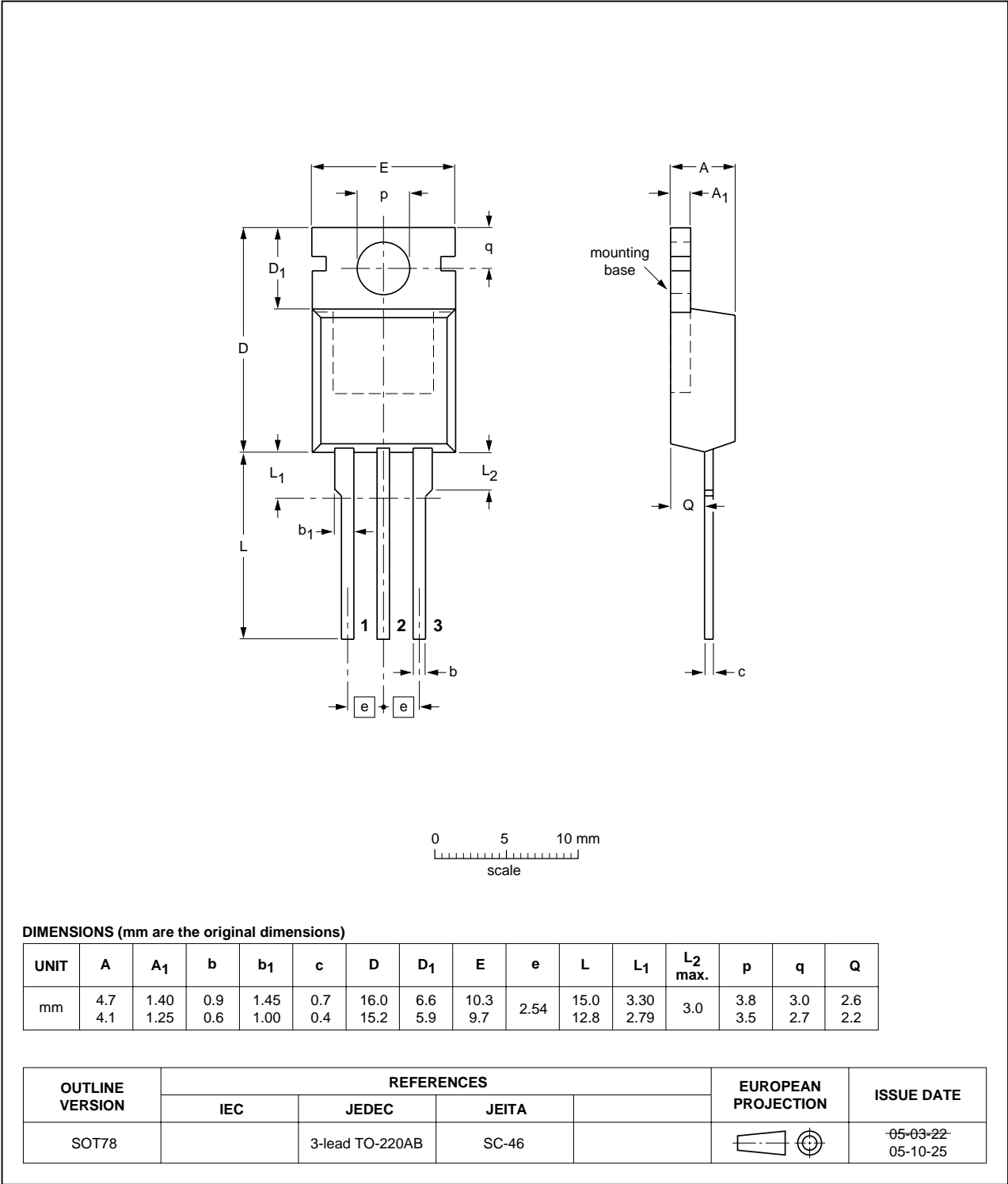


Fig 12. Package outline SOT78 (3-lead TO-220AB)

9. Revision history

Table 7. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BTA312_SER_CT_ET_1	20070406	Product data sheet	-	-

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Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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